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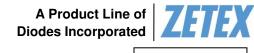












#### 140V PNP MEDIUM POWER LOW SATURATION TRANSISTOR IN SOT223

#### **Features**

- BV<sub>CEO</sub> > -140V
- I<sub>C</sub> = -4A High Continuous Collector Current
- I<sub>CM</sub> = -10A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < -120mV @ I<sub>C</sub> = -1A
- $R_{SAT} = 92m\Omega$  for a Low Equivalent On-Resistance
- h<sub>FE</sub> Specified up to -10A for a High Gain Hold-Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

# Application

- Motor Driving
- Line Switching
- High Side Switches
- Subscriber Line Interface Cards (SLIC)

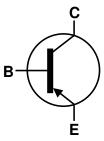
#### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic. "Green" molding Compound;
  UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

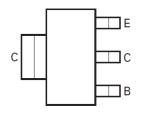
#### SOT223







Device Symbol



Top View Pin-Out

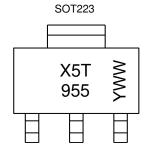
#### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZX5T955GTA	X5T955	7	12	1,000
ZX5T955GTC	X5T955	13	12	4,000

Notes:

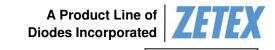
- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**



 $\begin{array}{l} \textrm{X5T 955} = \textrm{Product Type Marking Code} \\ \textrm{YWW} = \textrm{Date Code Marking} \\ \textrm{Y or } \overline{\textrm{Y}} = \textrm{Last Digit of Year (ex: 5= 2015)} \\ \textrm{WW or } \overline{\textrm{WW}} = \textrm{Week Code (01~53)} \\ \end{array}$ 





#### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-180	V
Collector-Emitter Voltage	$V_{CEO}$	-140	V
Emitter-Base Voltage	$V_{EBO}$	-7	V
Continuous Collector Current	Ic	-4	Α
Peak Pulse Current	I <sub>CM</sub>	-10	Α

#### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		3.0		
Power Dissipation	(Note 6)	D-	2.0	w	
Power Dissipation	(Note 7)	P <sub>D</sub>	1.6	VV	
	(Note 8)		1.2		
	(Note 5)		41.7		
Thermal Resistance, Junction to Ambient	(Note 6)	ь [	62.5		
Thermal nesistance, Junction to Ambient	(Note 7)	$\frac{67}{7)}$ $R_{\theta JA}$	$H_{\theta}JA$	78.1	°C/W
	(Note 8)		104		
Thermal Resistance Junction to Lead	(Note 9)	$R_{ hetaJL}$	10.5		
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C		

#### ESD Ratings (Note 10)

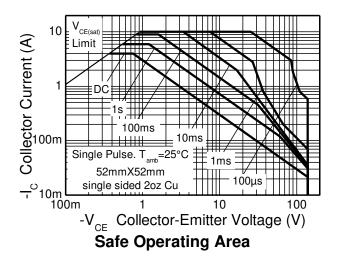
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

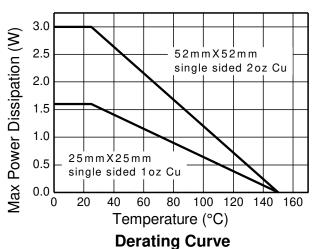
Notes:

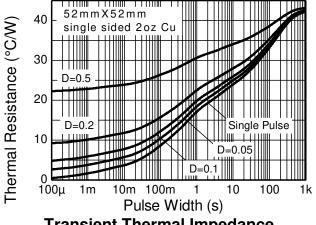
- 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
- 7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
- 8. Same as Note 5, except the device is mounted on minimum recommended pad layout.
- 9. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

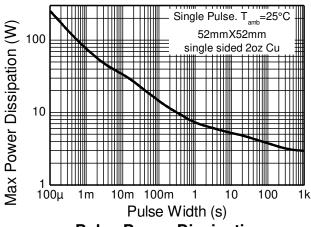


## **Thermal Characteristics and Derating Information**









**Pulse Power Dissipation** 



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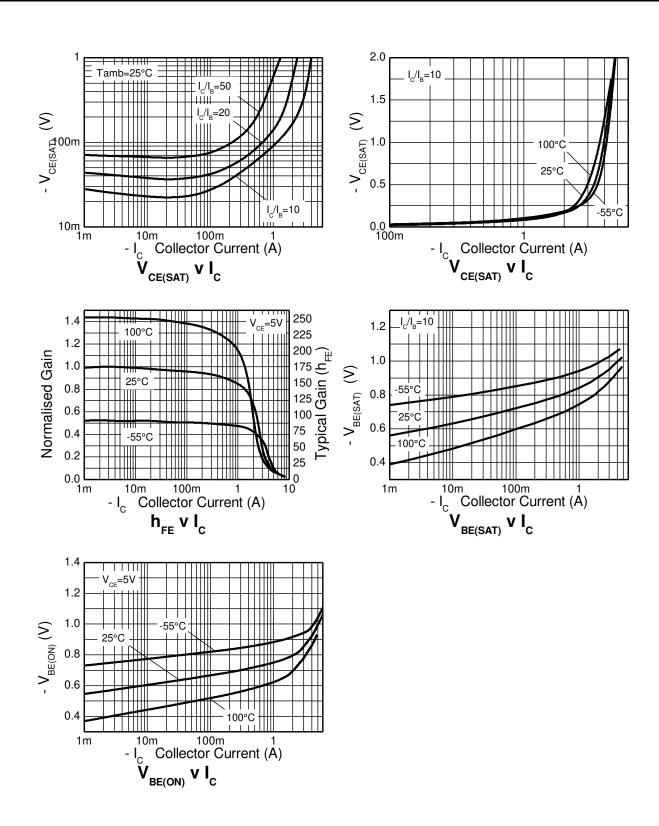
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_CBO$	-180	-200	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CER</sub>	-180	-200	-	V	$I_C = -1\mu A, R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	-140	-160	-	V	$I_C = -1mA$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-7	-8.3	-	V	$I_E = -100 \mu A$
Collector Cut-Off Current	I <sub>CBO</sub>	-	< -1 -	-20 -500	nA nA	V <sub>CB</sub> = -150V V <sub>CB</sub> = -150V, T <sub>A</sub> = +100°C
Collector Cut-Off Current	l <sub>CER</sub> R≤1kΩ	-	< -1 -	-20 -500	nA nA	V <sub>CB</sub> = -150V V <sub>CB</sub> = -150V, T <sub>A</sub> = +100°C
Emitter Cut-Off Current	I <sub>EBO</sub>	-	< -1	-10	nA	V <sub>EB</sub> = -6V
		100	225	-	-	$I_C = -10 \text{mA}, V_{CE} = -5 \text{V}$
DC Current Transfer Static Datic (Note 11)	h <sub>FE</sub>	100	200	300		$I_C = -1A$ , $V_{CE} = -5V$
DC Current Transfer Static Ratio (Note 11)		45	100	-		$I_C = -3A, V_{CE} = -5V$
		-	5	-		$I_C = -10A$ , $V_{CE} = -5V$
	V <sub>CE(sat)</sub>	-	-40	-60	mV	$I_C = -100 \text{mA}, I_B = -5 \text{mA}$
Collector-Emitter Saturation Voltage (Note 11)		-	-55	-80		$I_C = -0.5A$ , $I_B = -50mA$
Collector-Ethlitter Saturation Voltage (Note 11)		-	-85	-120	IIIV	$I_C = -1A$ , $I_B = -100mA$
		-	-275	-360		$I_C = -3A$ , $I_B = -300mA$
Base-Emitter Saturation Voltage (Note 11)	$V_{BE(sat)}$	-	-940	-1040	mV	$I_C = -3A$ , $I_B = -300mA$
Base-Emitter Turn-On Voltage (Note 11)	$V_{BE(on)}$	-	-830	-930	mV	$I_C = -3A$ , $V_{CE} = -5V$
Transitional Frequency (Note 11)	f <sub>T</sub>	-	120	-	MHz	$I_{C} = -100 \text{mA}, V_{CE} = -10 \text{V},$ f = 50 MHz
Output Capacitance	$C_obo$	-	33	-	pF	$V_{CB} = -10V$ , $f = 1MHz$
Switching Time	ton	-	42	-	ns	$V_{CC} = -50V, I_{C} = -1A,$
Owitering Time	t <sub>OFF</sub>	-	636	-	119	$I_{B1} = -I_{B2} = -100 \text{mA}$

Note: 11. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



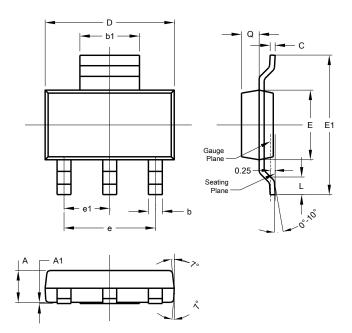
## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





## **Package Outline Dimensions**

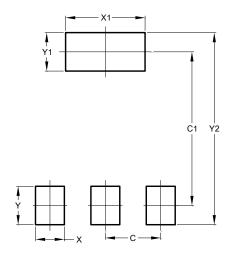
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
<b>A</b> 1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.





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